

5.0A Surface Mount Schottky Barrier Rectifiers

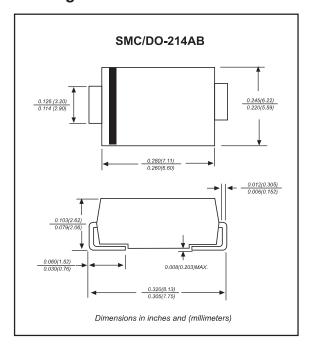
Features

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ For surface mounted applications
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Low power loss, high efficiency
- ◆ Built-in strain relief,ideal for automated placement
- High forward surge current capability
- High temperature soldering guaranteed: 260°C/10 seconds at terminals
- Compliant to RoHS 2.0

Mechanical data

- ◆ Case: JEDEC DO-214AB molded plastic body
- Terminals: Solder plated, solderable per MIL-STD-750, Method 2026
- ◆ Polarity: Color band denotes cathode end
- ◆ Mounting Position: Any

Package outline



Maximum ratings and Electrical Characteristics (AT T_A=25°C unless otherwise noted)

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Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	40	V
Average Rectified Forward Current (At Rated V_R , $T_C = 105$ °C)	I _{F(AV)}	5	Α
Peak Repetitive Forward Current (At Rated V_R , Square Wave, 20 KHz, $T_C = 80^{\circ}C$)	I _{FRM}	10	Α
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I _{FSM}	190	Α
Storage Temperature Range	Tstg	-65 to +150	°C
Operating Junction Temperature (Note 1)	TJ	-65 to +150	°C
Voltage Rate of Change (Rated V _R)	dv/dt	10,000	V/μs

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. The heat generated must be less than the thermal conductivity from Junction-to-Ambient: dP_D/dT_J < 1/R_{B,JA}.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction-to-Lead (Note 2) Thermal Resistance,	$R_{ hetaJL}$	12	°C/W
Junction-to-Ambient (Note 2)	$R_{ hetaJA}$	111	

2. Rating applies when surface mounted on the minimum pad size recommended.

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Maximum Instantaneous Forward Voltage (Note 3) (i _F = 5.0 A, T _C = 25°C)	V _F	0.50	V
Maximum Instantaneous Reverse Current (Note 3) (Rated dc Voltage, $T_C = 25^{\circ}C$) (Rated dc Voltage, $T_C = 100^{\circ}C$)	İR	0.3 15	mA

3. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.



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Rating and characteristic curves

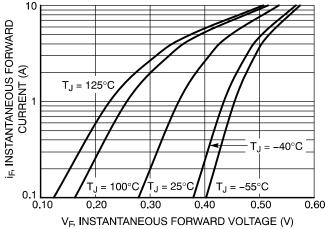
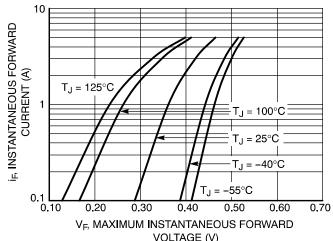


Figure 1. Typical Forward Voltage



VOLTAGE (V)
Figure 2. Maximum Forward Voltage

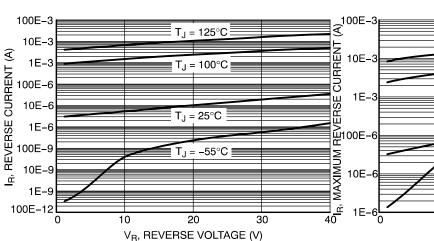


Figure 3. Typical Reverse Current

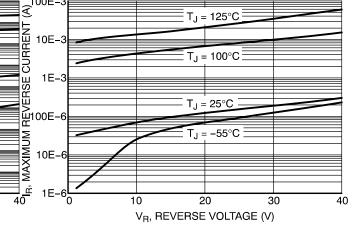


Figure 4. Maximum Reverse Current

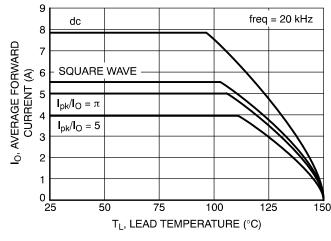


Figure 5. Current Derating

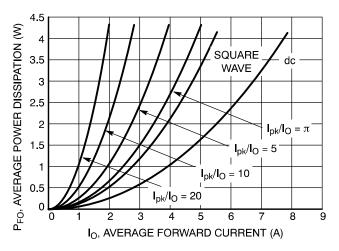


Figure 6. Forward Power Dissipation



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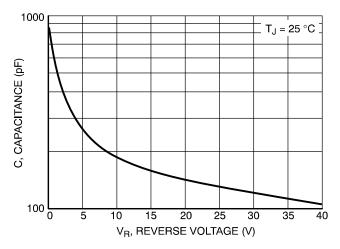


Figure 7. Capacitance

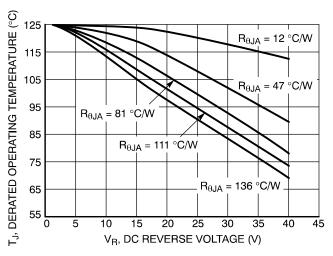


Figure 8. Typical Operating Temperature Derating

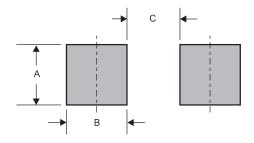
Pinning information

Pin	Simplified outline	Symbol
Pin1 cathode Pin2 anode	1 [12

Marking

Type number	Marking code	Example
MBRS540T3G-FS	B540	B540 Marking code

Suggested solder pad layout

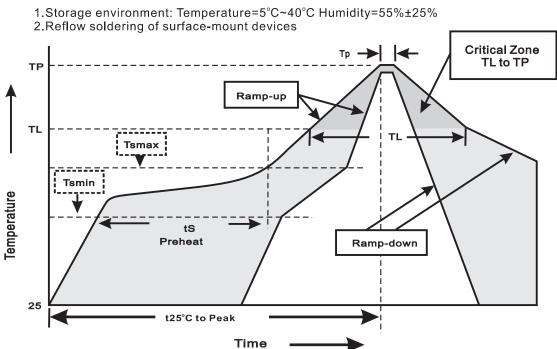


Dimensions in inches and (millimeters)

PACKAGE	А	В	С
SMC	0.132 (3.30)	0.100 (2.50)	0.176(4.40)

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Suggested thermal profiles for soldering processes



3.Reflow soldering

Profile Feature	Soldering Condition
Average ramp-up rate(TL to T _P)	<3°C/sec
Preheat -Temperature Min(Tsmin) -Temperature Max(Tsmax) -Time(min to max)(ts)	150°C 200°C 60~120sec
Tsmax to T∟ -Ramp-upRate	<3°C/sec
Time maintained above: -Temperature(TL) -Time(tL)	217°C 60~260sec
Peak Temperature(T _P)	255°C-0/+5°C
Time within 5°C of actual Peak Temperature(t _P)	10~30sec
Ramp-down Rate	<6°C/sec
Time 25°C to Peak Temperature	<6minutes